

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Sheu, *et al.* Docket No.: TSM03-0140  
Serial No.: 10/619,828 Art Unit: 2891  
Filed: July 15, 2003 Examiner: Movva, Amar  
Title: Self-Aligned MOSFET having an Oxide Region below the Channel

Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

**INFORMATION DISCLOSURE STATEMENT**

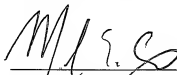
Dear Sir:

The Applicant wishes to bring to the attention of the U.S. Patent and Trademark Office the information noted on the enclosed form PTO/SB/08a, which may be considered material to the examination of the above-identified application. Copies of the U.S. Patents cited are not being submitted.

This Information Disclosure Statement is submitted under 37 C.F.R. §1.97(c) together with a \$180.00 fee under 37 C.F.R. §1.17(p) after the C.F.R. §1.97(b) time period, but before final action or notice of allowance, whichever occurs first.

Please charge the required fee of \$180.00 and any additional amount, or credit any overpayment to Deposit Acct. No. 50-1065 of the below mentioned firm.

Respectfully submitted,



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February 2, 2009

Date

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